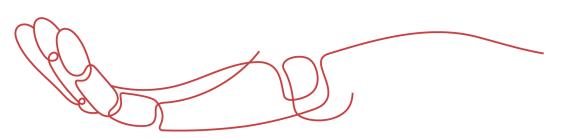




# **PRODUCT DATA SHEET**



To learn more about JGSEMI, please visit our website at







Datasheet

s Samples

Please note: Please check the JINGAO Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.jg-semi.cn. Please email any questions regarding the system integration to JINGAO\_questions@jgsemi.com.



1-Line Low Capacitance Bi-directional TVS Diode

### **Features**

• 400W peak pulse power (8/20µs)

• Ultra low capacitance: 0.6pF typical

• Ultra low leakage: nA leel

• Low operating voltage: 3.3V

· Low clamping voltage

• Protects one power line or data line

• Complies with following standards:

- IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-4 (EFT) 80A (5/50ns)

- IEC61000-4-5 (Lightning) 20A (8/20)

• RoHS Compliant

### **Applications**

- USB Ports
- SIM Ports
- Smart Phones
- · Wireless Systems
- Set-top box and digital TV
- Digital video interface (DVI)
- Ethernet 10/100/1000 Base T

#### **Mechanical Characteristics**

• Package: SOD-323

• Lead Finish: Matte Tin

Case Material: "Green" Molding Compound.

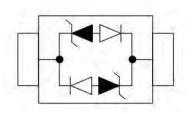
• UL Flammability Classification Rating 94V-0

• Quantity Per Reel:3,000pcs

Reel Size:7 inch



SOD-323



## **Absolute Maximum Ratings**(Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ррр	400	W
ESD per IEC 61000-4-2 (Air)	Vesd	± 30	Kv
ESD per IEC 61000-4-2 (Contact)	V ESD	± 30	IXV
Operating Temperature Range	TJ	-55 to +125	Ç
Storage Temperature Range	Тѕтл	-55 to +150	$^{\circ}$

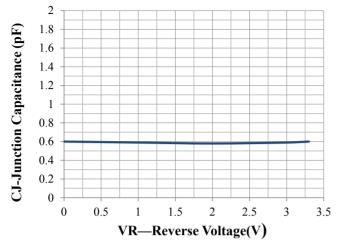


## Electrical Characteristics (TA=25°C unless otherwise specified)

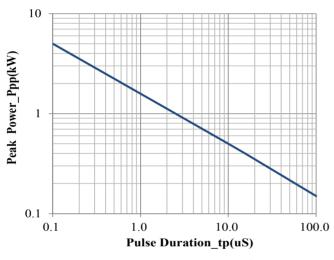
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VRWM	Reverse Working Peak Voltage				3.3	V
VBR	Reverse Breakdown Voltage	IT = 1mA	4		6	V
IR	Reverse Leakage Current	VRWM = 3.3V			0.2	μΑ
VC	Clamping Voltage	IPP = 1 A (8/20µs)			9	V
VC	Clamping Voltage	IPP = 20 A (8/20µs)			20	V
Cl	Capacitance	VR = 0V, f = 1MHz		0.6		pF



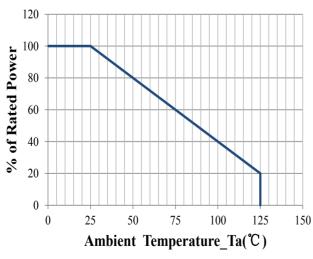
### Typical Performance Characteristics (TA=25°C unless otherwise Specified)



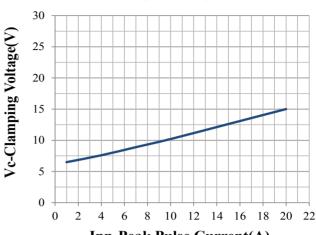
Junction Capacitance vs. Reverse Voltage



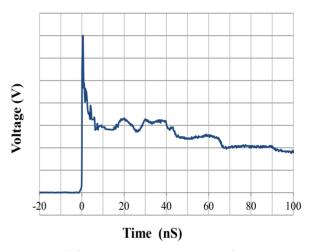
Peak Pulse Power vs. Pulse Time



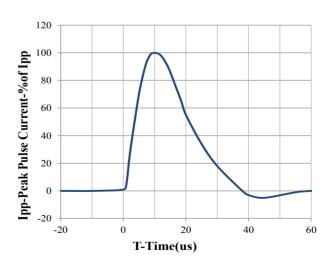
**Power Derating Curve** 



Ipp-Peak Pulse Current(A)
Clamping Voltage vs. Peak Pulse Current



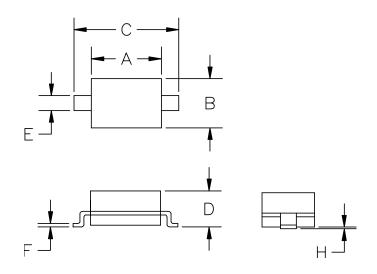
IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform

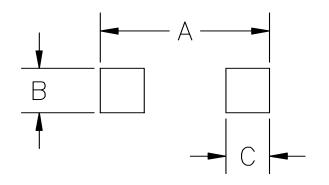


#### **SOD-323 Package Outline & Dimensions**



	DIMENSIONS				
SYM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
Α	1.50	1.80	0.060	0.071	
В	1.20	1.40	0.045	0.054	
С	2.30	2.70	0.090	0.107	
D	-	1.10	-	0.043	
Е	0.30	0.40	0.012	0.016	
F	0.10	0.25	0.004	0.010	
Н	-	0.10	-	0.004	

# **Suggested Land Pattern**



SYM	DIMENSIONS		
STW	MILLIMETERS	INCHES	
Α	3.15	0.120	
В	0.80	0.031	
С	0.80	0.031	



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